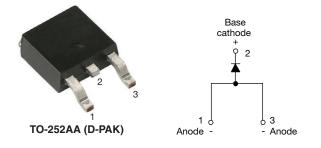
**Vishay Semiconductors** 

# Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



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PRODUCT SUMMARY							
Package	TO-252AA (D-PAK)						
I <sub>F(AV)</sub>	8 A						
V <sub>R</sub>	1000 V, 1200 V						
V <sub>F</sub> at I <sub>F</sub>	1.3 V						
I <sub>FSM</sub>	150 A						
t <sub>rr</sub>	80 ns						
T <sub>J</sub> max.	150 °C						
Diode variation	Single die						
Snap factor	0.6						

### **FEATURES**

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### APPLICATIONS

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

#### DESCRIPTION

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I <sub>F(AV)</sub>	Sinusoidal waveform	8	A							
V <sub>RRM</sub>		1000/1200	V							
I <sub>FSM</sub>		150	A							
V <sub>F</sub>	8 A, T <sub>J</sub> = 25 °C	1.3	V							
t <sub>rr</sub>	1 A, 100 A/µs	80	ns							
TJ	Range	-40 to +150	°C							

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-8EWF10S-M3	1000	1100	4						
VS-8EWF12S-M3	1200	1300	4						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER SYMBOL		TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 96 ^{\circ}C$ , 180° conduction half sine wave	8						
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied	125	А					
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	150						
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	78	A <sup>2</sup> s					
Maximum 1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	110	A-5					
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s					

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
Maximum forward voltage drop	V <sub>FM</sub>	8 A, T <sub>J</sub> = 25 °C		1.3	V			
Forward slope resistance	r <sub>t</sub>	T.I = 150 °C		25.6	mΩ			
Threshold voltage	V <sub>F(TO)</sub>	IJ = 150 C		0.93	V			
Maximum reverse leakage ourrent	1	T <sub>J</sub> = 25 °C	25 °C		mA			
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	$V_R = Rated V_{RRM}$	4	ША			

RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •			
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> at 8 A <sub>pk</sub>	270	ns	I <sub>FM</sub>			
Reverse recovery current	I <sub>rr</sub>	25 A/µs	4.2	А	$\left  \begin{array}{c} I_{rr} \\ I_{a} \\ I_{b} \\ I_{$			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	1	μC				
Snap factor	S		0.6					

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W				
Typical thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> <sup>(1)</sup>		50	0/10				
Approvimate weight			1	g				
Approximate weight			0.03	oz.				
Marking davias		Case style TO-252AA (D-PAK)	8EWF10S					
Marking device		Case signe 10-202AA (D-PAR)	8EWF12S					

Note

<sup>(1)</sup> When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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**RMS** limit

Conduction period

at 50 Hz 0.0100 s

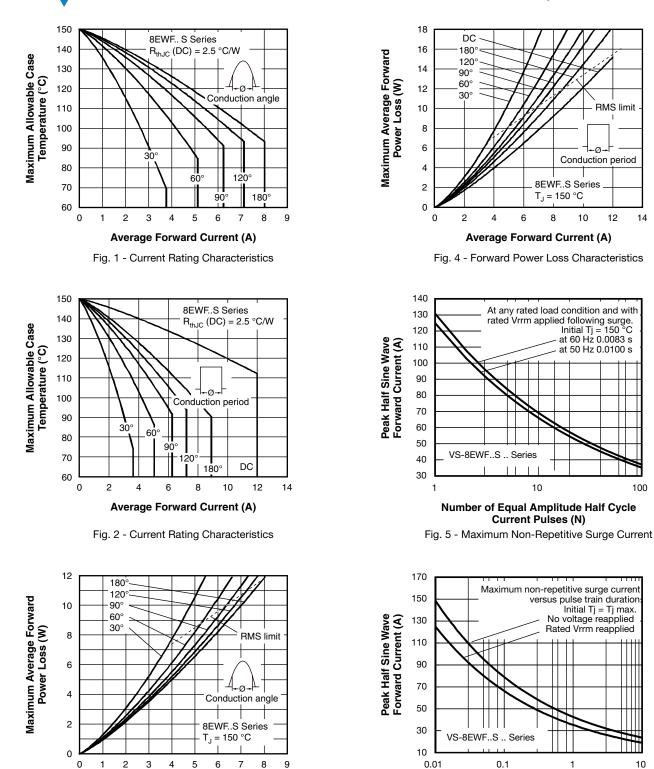
Initial Tj = Tj max

12

14

100

10



Pulse Train Duration (s)

Fig. 6 - Maximum Non-Repetitive Surge Current

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Average Forward Current (A)

Fig. 3 - Forward Power Loss Characteristics

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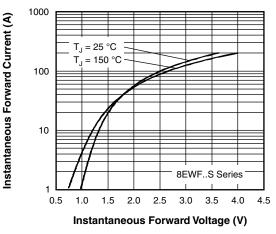
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Fig. 7 - Forward Voltage Drop Characteristics

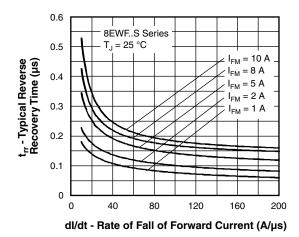


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

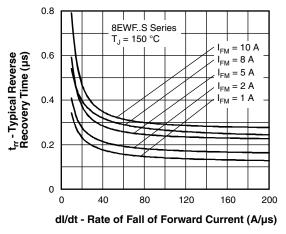


Fig. 9 - Recovery Time Characteristics,  $T_J$  = 150  $^\circ C$ 

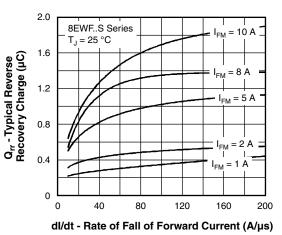
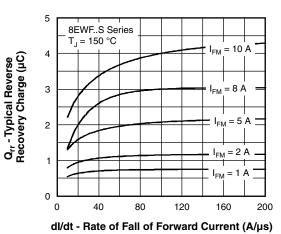


Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C





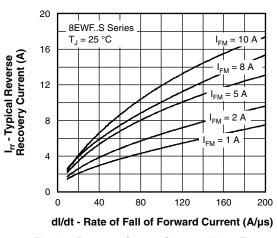


Fig. 12 - Recovery Current Characteristics,  $T_{\rm J}$  = 25  $^\circ\text{C}$ 

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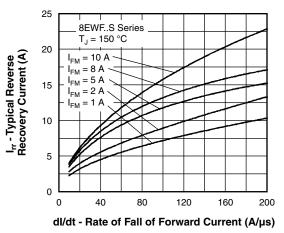


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

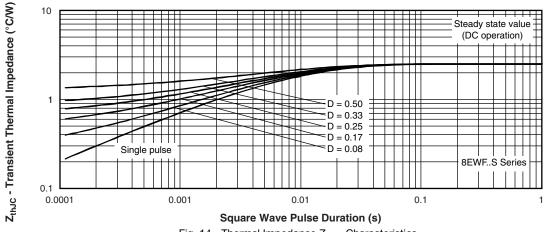


Fig. 14 - Thermal Impedance ZthJC Characteristics

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### **ORDERING INFORMATION TABLE**

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Device code	VS-	8	Е	w	F	12	S	TR	-M3
		2	3	4	5	6	7	8	9
	1 -	Visl	nay Sem	niconduc	ctors pro	oduct			
	2 - Current rating (8 = 8 A)								
	<b>3</b> - Circuit configuration:								
		E = single diode							
	4 -	Pac	kage:						
		W =	D-PAK	,					
	5 -	. Тур	e of silio	con:					
		F =	fast sof	t recove	ry rectif				
	6 -	- Volt	age coo	le x 100	= V <sub>RRN</sub>		10 = 10 12 = 12		
	7 -	S =	surface	mounta	able		12 - 12	00 V	
	8 -	• TI	R = tape	and ree	el				
		• TI	RR = ta	be and r	eel (rigł	nt orient	ed)		
		• TI	<ul> <li>TRL = tape and reel (left oriented)</li> </ul>						
	9 -	Env	ironmer	ntal digit	:				

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-8EWF10S-M3	75	3000	Antistatic plastic tubes						
VS-8EWF10STR-M3	2000	2000	13" diameter reel						
VS-8EWF10STRL-M3	3000	3000	13" diameter reel						
VS-8EWF10STRR-M3	3000	3000	13" diameter reel						
VS-8EWF12S-M3	75	3000	Antistatic plastic tubes						
VS-8EWF12STR-M3	2000	2000	13" diameter reel						
VS-8EWF12STRL-M3	3000	3000	13" diameter reel						
VS-8EWF12STRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95627						
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95552						

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D-PAK (TO-252AA) "M"

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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